



SMALL SIGNAL COMPLEMENTARY PRE-BIASED DUAL TRANSISTOR

Features

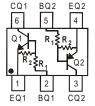
- Epitaxial Planar Die Construction
- Built-In Biasing Resistors
- Surface Mount Package Suited for Automated Assembly
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

R1(NOM)	R2(NOM)
10kΩ	47kΩ



Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)



Device Schematic

Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ACX114YUQ-7R	Automotive	1Y2	7	8	3,000
ACX114YUQ-13R	Automotive	1Y2	13	8	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

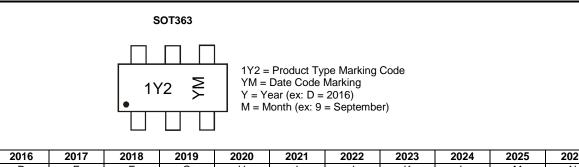
 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product_compliance_definitions/.

5. -13R are parts rotated in the pocket tape by +180°. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Year	2016	2017	2018	2019	202	20 20)21	2022	2023	2024	2025	2026
Code	D	E	F	G	Н			J	K	L	М	N
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	l Seb	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



Absolute Maximum Ratings - NPN Section (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage <pin: (1)="" (6)="" to=""></pin:>	V _{CC}	50	V
Input Voltage <pin: (1)="" (2)="" to=""></pin:>	V _{IN}	-6 to +40	V
Output Current	Io	70	mA
Output Current	I _C (Max)	100	mA

Absolute Maximum Ratings - PNP Section (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage <pin: (3)="" (4)="" to=""></pin:>	V _{CC}	-50	V
Input Voltage <pin: (4)="" (5)="" to=""></pin:>	V _{IN}	+6 to -40	V
Output Current	lo	-70	mA
Output Current	I _C (Max)	-100	mA

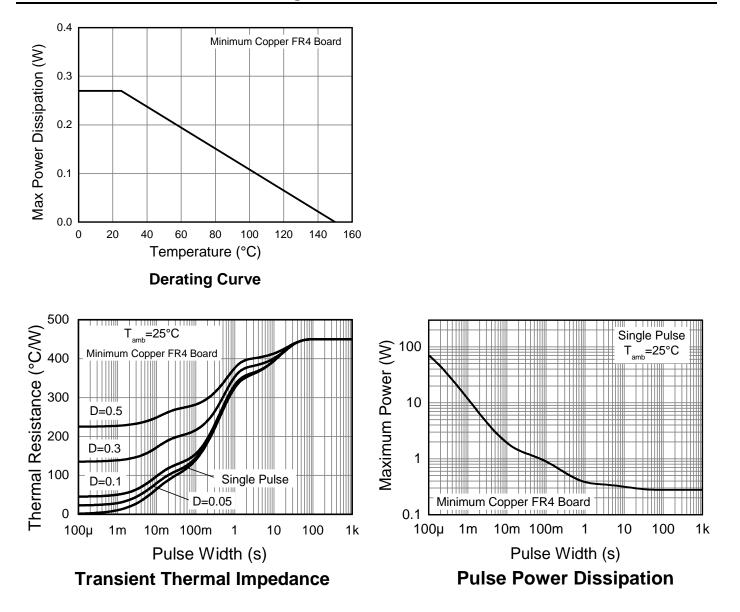
Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 6 & 7)	PD	270	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{ heta}$ JA	450	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 6. Mounted on FR4 PC Board with minimum recommended pad layout. 7. 150mW per element must not be exceeded.



Thermal Characteristics and Derating Information





Electrical Characteristics - NPN Section (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	VI(OFF)	0.3		_	V	$V_{CC} = 5V, I_{O} = 100\mu A$
input voltage	V _{I(ON)}			1.4	v	$V_0 = 0.3V, I_0 = 1mA$
Output Voltage	V _{O(ON)}	—	0.1	0.3	V	$I_0/I_1 = 5mA / 0.25mA$
Input Current	lı –	_	_	0.88	mA	$V_1 = 5V$
Output Current	I _{O(OFF)}	_	_	0.5	μA	$V_{CC} = 50V, V_{I} = 0V$
DC Current Gain (Note 8)	GI	80	_	_	_	$V_0 = 5V, I_0 = 10mA$
Input Resistor (R1) Tolerance	ΔR_1	-30	_	+30	%	—
Resistance Ratio Tolerance	$\Delta R_2/R_1$	-20		+20	%	—
Gain-Bandwidth Product	f⊤	_	250		MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz

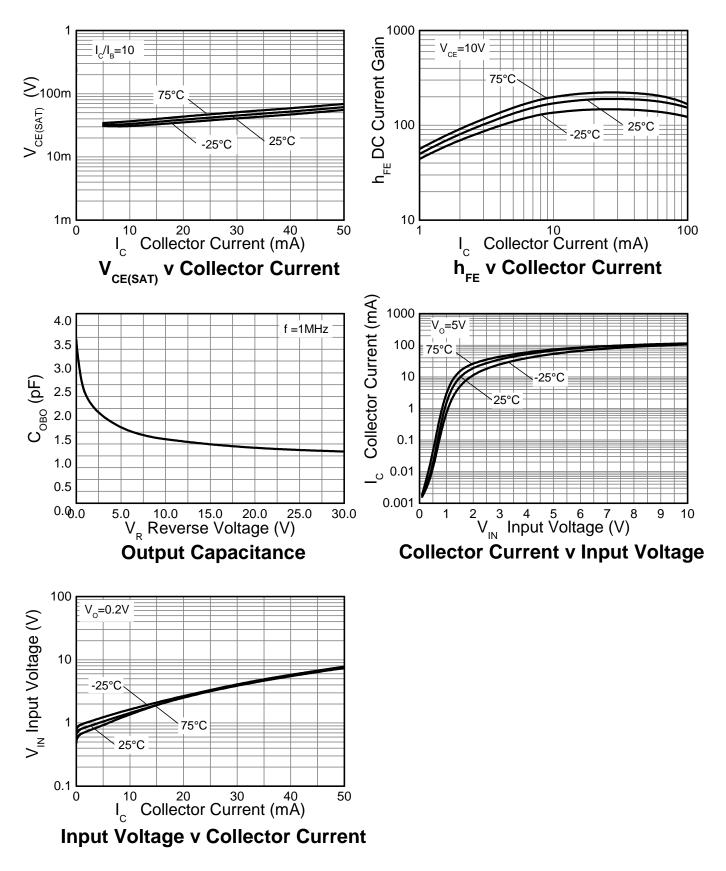
Electrical Characteristics - PNP Section (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	VI(OFF)	-0.3	_	—	V	$V_{CC} = -5V, I_{O} = -100\mu A$
Input voltage	V _{I(ON)}	—		-1.4	v	$V_0 = -0.3V, I_0 = -1mA$
Output Voltage	V _{O(ON)}	—	-0.1	-0.3	V	I _O /I _I = -5mA / -0.25mA
Input Current	lı	—	_	-0.88	mA	V _I = -5V
Output Current	I _{O(OFF)}	_		-0.5	μA	$V_{CC} = -50V, V_{I} = 0V$
DC Current Gain (Note 8)	GI	80	_	_	_	$V_0 = -5V, I_0 = -10mA$
Input Resistor (R1) Tolerance	ΔR_1	-30		+30	%	—
Resistance Ratio Tolerance	$\Delta R_2/R_1$	-20		+20	%	—
Gain-Bandwidth Product	f⊤		250		MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

Note: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

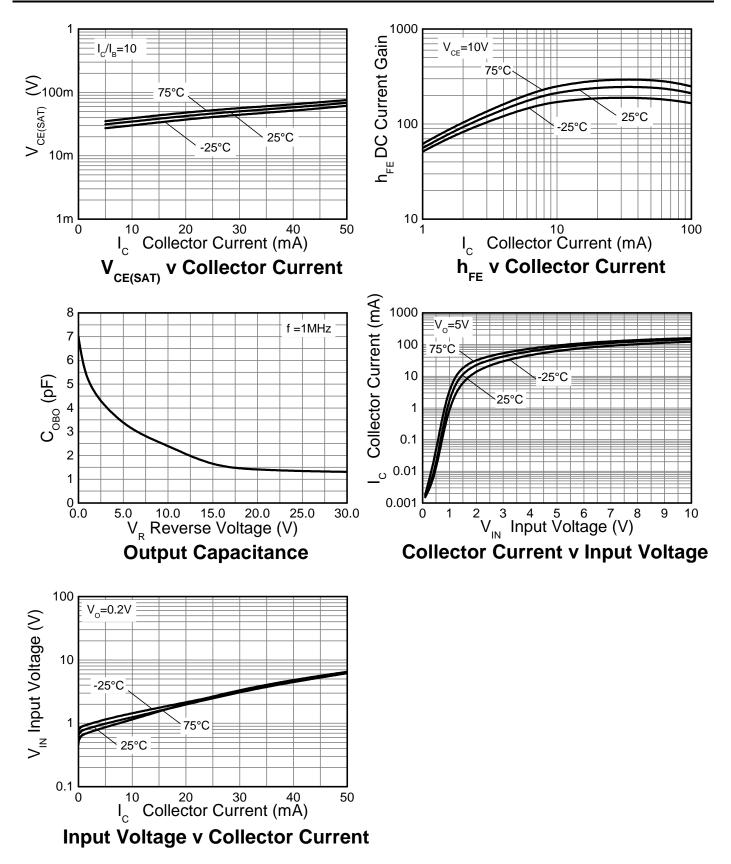


Typical Electrical Characteristics – NPN Section (@T_A = +25°C, unless otherwise specified.)





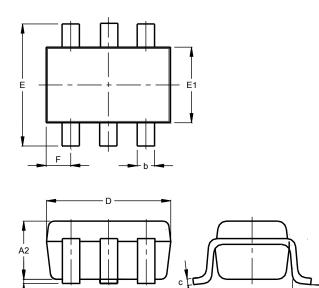
Typical Electrical Characteristics – PNP Section (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

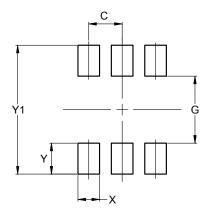


	SOT363									
Dim	Min	Max	Тур							
A1	0.00	0.10	0.05							
A2	0.90	1.00	1.00							
b	0.10	0.30	0.25							
С	0.10	0.22	0.11							
D	1.80	2.20	2.15							
Е	2.00	2.20	2.10							
E1	1.15	1.35	1.30							
е	C).650 E	SC							
F	0.40	0.45	0.425							
L	0.25	0.40	0.30							
а	0°	8°								
All	Dimen	sions	in mm							

Suggested Pad Layout

A1

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Y	0.600
Y1	2.500



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